

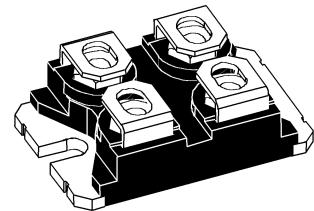
# HiPerFRED™ Epitaxial Diode with soft recovery

**I<sub>FAV</sub> = 2x 35 A**  
**V<sub>RRM</sub> = 600 V**  
**t<sub>rr</sub> = 20 ns**

V <sub>RSM</sub>	V <sub>RRM</sub>	Type
V	V	
600	600	DSEP 2x 35-06C



miniBLOC, SOT-227 B



Symbol	Test Conditions	Maximum Ratings	
I <sub>FRMS</sub>		49	A
I <sub>FAVM</sub>	T <sub>C</sub> = 80°C; rectangular, d = 0.5	35	A
I <sub>FRM</sub>	t <sub>p</sub> < 10 µs; rep. rating, pulse width limited by T <sub>VJM</sub>	tbd	A
I <sub>FSM</sub>	T <sub>VJ</sub> = 45°C; t <sub>p</sub> = 10 ms (50 Hz), sine	300	A
E <sub>AS</sub>	T <sub>VJ</sub> = 25°C; non-repetitive I <sub>AS</sub> = 3 A; L = 180 µH	1.2	mJ
I <sub>AR</sub>	V <sub>A</sub> = 1.5·V <sub>R</sub> typ.; f = 10 kHz; repetitive	0.3	A
T <sub>VJ</sub>		-40...+150	°C
T <sub>VJM</sub>		150	°C
T <sub>stg</sub>		-40...+150	°C
P <sub>tot</sub>	T <sub>C</sub> = 25°C	165	W
V <sub>ISOL</sub>	50/60 Hz, RMS I <sub>ISOL</sub> ≤ 1 mA	2500	V~
M <sub>d</sub>	mounting torque (M4) terminal connection torque (M4)	1.1-1.5/9-13 1.1-1.5/9-13	Nm/lb.in. Nm/lb.in.
Weight	typical	30	g

Symbol	Test Conditions	Characteristic Values	
		typ.	max.
I <sub>R</sub> ①	V <sub>R</sub> = V <sub>RRM</sub> ; T <sub>VJ</sub> = 25°C T <sub>VJ</sub> = 150°C	0.25 1.0	mA mA
V <sub>F</sub> ②	I <sub>F</sub> = 35 A; T <sub>VJ</sub> = 150°C T <sub>VJ</sub> = 25°C	1.83 2.50	V V
R <sub>thJC</sub> R <sub>thCH</sub>	with heatsink compound	0.1	0.9 K/W K/W
t <sub>rr</sub>	I <sub>F</sub> = 1 A; -di/dt = 300 A/µs; V <sub>R</sub> = 30 V; T <sub>VJ</sub> = 25°C	20	ns
I <sub>RM</sub>	V <sub>R</sub> = 100 V; I <sub>F</sub> = 50 A; -di <sub>F</sub> /dt = 100 A/µs T <sub>VJ</sub> = 100°C	4.5	7.0 A

Pulse test: ① Pulse Width = 5 ms, Duty Cycle < 2.0 %  
 ② Pulse Width = 300 µs, Duty Cycle < 2.0 %

Data according to IEC 60747 and per diode unless otherwise specified

IXYS reserves the right to change limits, test conditions and dimensions.

## Features

- International standard package miniBLOC
- Isolation voltage 2500 V~
- UL registered E 72873
- 2 independent FRED in 1 package
- Planar passivated chips
- Very short recovery time
- Extremely low switching losses
- Low I<sub>RM</sub>-values
- Soft recovery behaviour

## Applications

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

## Advantages

- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low I<sub>RM</sub> reduces:
  - Power dissipation within the diode
  - Turn-on loss in the commutating switch

Dimensions see CD "Databook 2000"